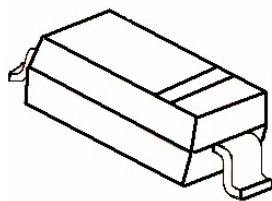


SOD-323



Marking: BAT42WS: S7
BAT43WS: S8

SOD-323 Plastic-Encapsulate Schottky Barrier Diode

特征 Features

- 大电流承受能力。High Current Capability
- 正向压降低。Low Forward Voltage Drop

机械数据 Mechanical Data

- 封装: SOD-323 封装 SOD-323 Small Outline Plastic Package
- 极性: 色环端为负极 Polarity: Color band denotes cathode end
- 环氧树脂 UL 易燃等级 Epoxy UL: 94V-0
- 安装位置: 任意 Mounting Position: Any

极限值和温度特性(TA = 25℃ 除非另有规定)

Maximum Ratings & Thermal Characteristics (Ratings at 25℃ ambient temperature unless otherwise specified.)

参数 Parameters	符号 Symbol	BAT42WS/BAT43WS	单位 Unit
最大可重复峰值反向电压 Maximum repetitive peak reverse voltage	VRRM	30	V
最大均方根电压 Maximum RMS voltage	VRMS	21	V
最大直流阻断电压 Maximum DC blocking voltage	VDC	30	V
最大正向平均整流电流 Maximum average forward rectified current	IFM	200	mA
峰值重复正向电流 Repetitive Peak Forward Current @t<1.0s	IFRM	500	mA
峰值正向浪涌电流 8.3ms 单一正弦半波 Peak forward surge current 8.3 ms single half sine-wave	IFSM	4.0	A
典型热阻 Typical thermal resistance	RθJA	500	℃/W
功率消耗 Power Dissipation	PD	200	mW
结温 Junction Temperature	Tj	125	℃
存储温度 Storage temperature range	TSTG	-55-+150	℃

电特性 (TA = 25℃ 除非另有规定)

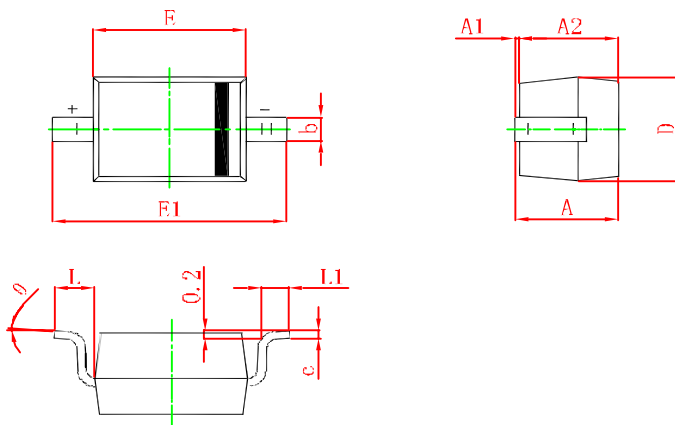
Electrical Characteristics (Ratings at 25℃ ambient temperature unless otherwise specified).

参数 Parameters	符号 Symbol	测试条件 Test conditions	Min	Typ	Max	单位 Unit
最大正向电压 Maximum forward voltage	BAT42WS/BAT43WS	VF	IF = 200mA		1.0	V
	BAT42WS	VF	IF = 10mA		0.40	
		VF	IF = 50mA		0.65	
	BAT43WS	VF	IF = 2.0mA	0.26	0.33	
		VF	IF = 15mA		0.45	
最大反向电压 Maximum reverse breakdown voltage	VR	IR=10uA	30			V
最大反向电流 Maximum reverse current	IR	VR=25V			0.5	uA
典型结电容 Type junction capacitance	Cj	VR = 1.0V, f = 1MHz			10	pF
反向恢复时间 Reverse recovery time	trr	IF=IR=10mA Irr=0.1xIR, RL=100 Ω			5	nS

BAT42WS-BAT43WS

SOD-S23 PACKAGE OUTLINE Plastic surface mounted package

SOD-323



Symbol	Min.(mm)	Max.(mm)
A		1.000
A1	0.000	0.100
A2	0.800	0.900
b	0.250	0.350
c	0.080	0.150
D	1.200	1.400
E	1.600	1.800
E1	2.500	2.700
L	0.475REF	
L1	0.250	0.400
θ	0°	8°